The RF Line
CATV Amplifier Module

MHW7185CL

750 MHz
19.2 dB GAIN
110–CHANNEL
CATV AMPLIFIER

Features

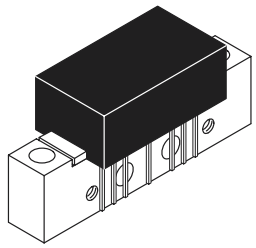
- Specified for 77– and 110–Channel Loading
- Lower DC Current Requirements
- Excellent Distortion Performance
- Excellent DC Current Stability over Temperature
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

Applications

- CATV Systems Operating in the 40 to 750 MHz Frequency Range
- Output Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications
- Amplifier Requiring Lower Power Dissipation While Maintaining Excellent Output Performance

Description

- 24 Vdc Supply, 40 to 750 MHz, CATV Forward Power Doubler Amplifier



CASE 714Y–03, STYLE 1

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V_{in}	+70	dBmV
DC Supply Voltage	V_{CC}	+28	Vdc
Operating Case Temperature Range	T_C	–20 to +100	°C
Storage Temperature Range	T_{stg}	–40 to +100	°C

ELECTRICAL CHARACTERISTICS (V_{CC} = 24 Vdc, T_C = +30°C, 75 Ω system unless otherwise noted)

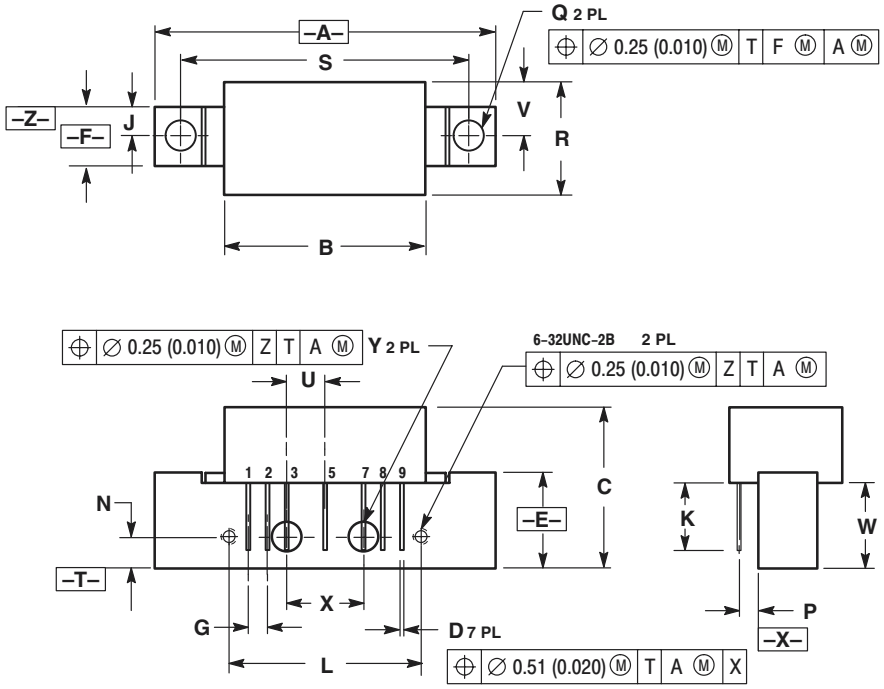
Characteristic		Symbol	Min	Typ	Max	Unit
Frequency Range		BW	40	—	750	MHz
Power Gain	50 MHz 750 MHz	G_p	18 18.7	18.5 19.2	19 19.7	dB
Slope	40–750 MHz	S	0.3	0.6	1.3	dB
Gain Flatness (40–750 MHz, Peak to Valley)		G_F	—	0.3	0.6	dB
Return Loss — Input/Output (Z_o = 75 Ohms)	 @ 40 MHz @ f > 40 MHz (Derate)	IRL/ORL	 20 —	 — —	 — 0.007	 dB dB/MHz
Composite Second Order (V_{out} = +44 dBmV/ch., Worst Case)	 110–Channel FLAT 77–Channel FLAT	 CSO_{110} CSO_{77}	 — —	 –70 –83	 –64 –68	dBc
Cross Modulation Distortion @ Ch 2 (V_{out} = +44 dBmV/ch., FM = 55 MHz)	 110–Channel FLAT 77–Channel FLAT	 XMD_{110} XMD_{77}	 — —	 –66 –69	 –63 –67	dBc

ELECTRICAL CHARACTERISTICS — continued (V_{CC} = 24 Vdc, T_C = +30°C, 75 Ω system unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
Composite Triple Beat (V_{out} = +44 dBmV/ch., Worst Case)	110–Channel FLAT 77–Channel FLAT	CTB_{110} CTB_{77}	— —	–63.5 –70	–61 –68	dBc
Noise Figure	50 MHz 550 MHz 750 MHz	NF	— — —	5.3 5.8 6.5	6.2 — 7.5	dB
DC Current (V_{DC} = 24 V, T_C = –20 to +100°C)		I_{DC}	345	370	385	mA

NOTES

PACKAGE DIMENSIONS



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	----	1.775	----	45.08
B	----	1.085	----	27.56
C	----	0.840	----	21.34
D	0.018	0.022	0.46	0.56
E	0.465	0.510	11.81	12.95
F	0.300	0.325	7.62	8.25
G	0.100 BSC		2.54 BSC	
J	0.156 BSC		3.96 BSC	
K	0.315	0.355	8.00	8.50
L	1.00 BSC		25.40 BSC	
N	0.165 BSC		4.19 BSC	
P	0.100 BSC		2.54 BSC	
Q	0.148	0.168	3.76	4.27
R	----	0.600	----	15.24
S	1.500 BSC		38.10 BSC	
U	0.200 BSC		5.08 BSC	
V	---	0.250	---	6.35
W	0.435	0.450	11.05	11.43
X	0.400 BSC		10.16 BSC	
Y	0.152	0.163	3.85	4.15

STYLE 1:
PIN 1. RF INPUT
2. GROUND
3. GROUND
4. DELETED
5. VDC
6. DELETED
7. GROUND
8. GROUND
9. RF OUTPUT

CASE 714Y–03
ISSUE D

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